TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA2111N,TA2111F,TA2111FN

3 V AM/FM 1 Chip Tuner IC

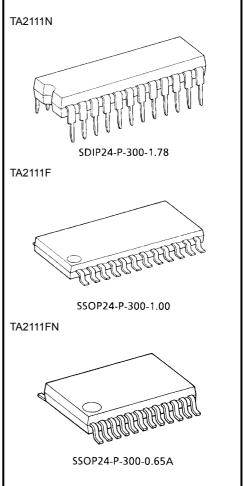
TA2111N/F/FN are AM/FM 1 chip tuner ICs, which are designed for portable radios and 3 V Head phone radios.

FM local oscillation voltage is set up low relativity, for NEW

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Features

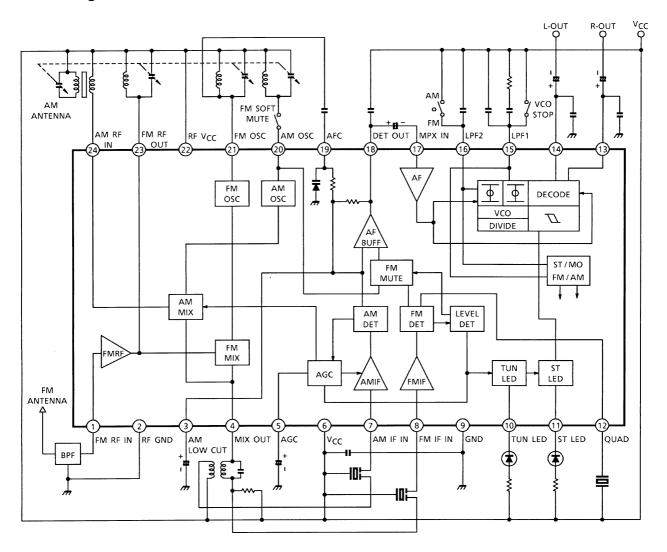
- For NEW FCC.
- AM Detector coil, FM IFT, IF coupling condenser are not needed.
- For adopting ceramic discriminator, it is not necessary to adjust the FM quad detector circuit.
- Built-in FM MPX VCO circuit.
- Built-in varactor diode for AFC.
- Built-in AM low cut circuit.
- Low supply current. ($V_{CC} = 3 \text{ V}$, $T_a = 25^{\circ}\text{C}$) I_{CCq} (FM) = 9.0 mA (typ.) I_{CCq} (AM) = 5.0 mA (typ.)
- Operating supply voltage range: VCC = 1.8~7 V (Ta = 25°C)



Weight SDIP24-P-300-1.78: 1.2 g (typ.) SSOP24-P-300-1.00: 0.31 g (typ.) SSOP24-P-300-0.65A: 0.14 g (typ.)

Note 1: Handle with care to prevent devices from deteriorations by static electricity.

Block Diagram



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Explanation of Terminals (Terminal voltage at no signal with test circuit, V_{CC} = 3 V, Ta = 25°C)

Pin	Characteristics	Internal Circuit	Terminal Voltage (Typ.) (V)		
No.	Characteristics	mema orcat	AM	FM	
1	FM-RF IN	1	0	0.8	
2	RF GND (GND for FM RF, FM OSC stage)	_	0	0	
3	AM LOW CUT	$\begin{array}{c} \text{FM DET} \\ \text{AM} \\ \text{DET} \\ \text{10k}\Omega \\ \text{GND} \end{array} \begin{array}{c} 100 \text{k}\Omega \\ \text{3} \\ \text{2 rf GND} \end{array}$	1.0	0.8	
4	MIX OUT	VCC 6 FM MIX AM MIX RF GND 2 9 GND	3.0	2.9	
5	AGC (AM AGC)	VCC 6 C C C C C C C C C C C C C C C C C	0	0	
6	V _{CC} (V _{CC} for AM, FM IF, FM MPX stage)	_	3.0	3.0	
7	AM IF IN	GND 9	2.3	2.6	

Pin	Characteristics	Internal Circuit	Termina (Typ	l Voltage .) (V)
No.			AM	FM
8	FM IF IN	VCC (6)	3.0	3.0
9	GND (GND for AM, FM IF, FM MPX stage)	_	0	0
10	TUN LED (Tuning LED)	GND 9	_	ı
11	ST LED (Stereo LED)	19kHz ————————————————————————————————————	_	-
12	QUAD (FM QUAD. Detector)	V _{CC} (6)	2.5	2.2
13 14	R-OUT (R-ch Output) L-OUT (L-ch Output)	V _{CC} (6) (13/14) (2) (3/14) (3/14) (3/14) (4/14) (1.2	1.2

Pin Characteristics		Internal Circuit	Termina (Typ	l Voltage .) (V)
NO.			AM	FM
15	LPF1 • LPF terminal for synchronous Detector • VCO stop terminal V15 = V _{CC} → VCO STOP	15 DC AMP	2.3	2.3
16	LPF2 • LPF terminal for phase Detector • Bias terminal for AM/FM SW circuit V16 = V _{CC} → AM V16 = OPEN → FM	16 AM/FM SW	3	2.2
17	MPX IN	(17)————————————————————————————————————	0.7	0.7
18	DET OUT	VCC (E) AM FM FM T50Ω (BLOW-FM, HIGH-AM) (BLOW-AM), HIGH-FM	1.0	0.9

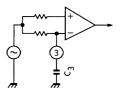
Pin Characteristics		Internal Circuit	Terminal Voltage (Typ.) (V)		
No.			AM	FM	
19	AFC	cf. pin 3	_	_	
20	AM OSC	V _{CC} (6) (7) (8) (8) (8) (8) (8) (8) (8) (8) (8) (8	3.0	3.0	
21	FM OSC	RF V _{CC} (22) GND (9)	3.0	3.0	
22	RF V _{CC} (V _{CC} for FM OSC stage)	_	3.0	3.0	
23	FM RF OUT	cf. pin 1	3.0	3.0	
24	AM RF IN	V _{CC} 6 AGC 29 GND 9	3.0	3.0	

Application Note

1. AM low-cut circuit

- The AM Low-Cut action is carried out by the bypass of the high frequency component of the positive-feedback signal at the AF AMP stage.

 The external capacitor: C₃ by-passes this component.
- The cut-off frequency f_L is determined by the internal resistance 10 k Ω (typ.) and the external capacitor C_3 as following;



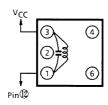
$$f_L = \frac{1}{2 \times \pi \times 10 \times 10^3 \times C_3} \text{ (Hz)}$$

- In the case of the AM Low-Cut function is not needed, set up the value of C_3 over 1 μ F. In the condition of $C_3 \ge 1$ μ F, the frequency characteristic has flat response at the low frequency.
- In FM mode, C3 is a capacitor for AFC Low-Pass filter circuit.

2. FM detection circuit

For the FM detection circuit, detection coil is able to use instead of ceramic discriminator. Recommended circuit and recommended coil are as follows. In this case, please take care that V_{in} (lim.) falls a little.





Toot Fraguenay	Co	0		Tu	rns		Wire	Reference
Test Frequency	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		(pF)	Reference				
10.7 MHz	51	45	_	_	30	_	0.08 UEW	TOKO Co., Ltd. 600BEAS-10018Z

Maximum Ratings (Ta = 25°C)

Characteristi	cs	Symbol	Rating	Unit	
Supply voltage	V _{CC}	8	V		
LED current		ILED	10	mA	
LED voltage	VLED	V			
	TA2111N		1200		
Power dissipation	TA2111F	P _D (Note 2)	400	mW	
	TA2111FN		500	*	
Operating temperature		T _{opr}	-25~75	°C	
Storage temperature	T _{stg}	-55~150	°C		

Note 2: Derated above Ta = 25°C in the proportion of 9.6 mW/°C for TA2111N, of 3.2 mW/°C for TA2111F and of 4 mW/°C for TA2111FN.

Electrical Characteristics

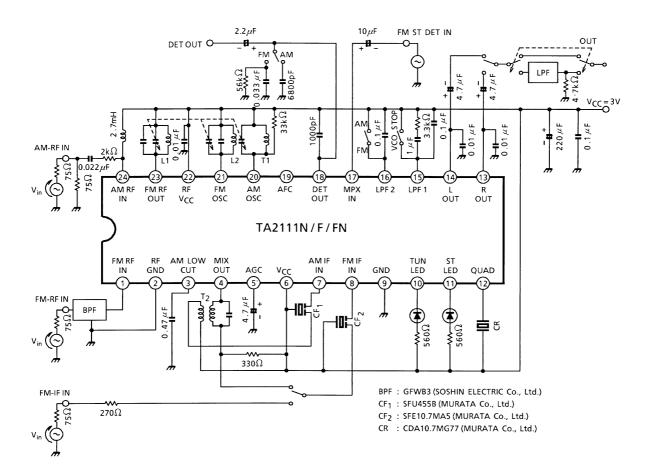
unless otherwise specified, Ta = 25°C, V_{CC} = 3 V,

F/E : f = 98 MHz, $f_m = 1$ kHz FM IF : f = 10.7 MHz, $\Delta f = \pm 22.5$ kHz, $f_m = 1$ kHz AM : f = 1 MHz, MOD = 30%, $f_m = 1$ kHz

 $MPX : f_m = 1 kHz$

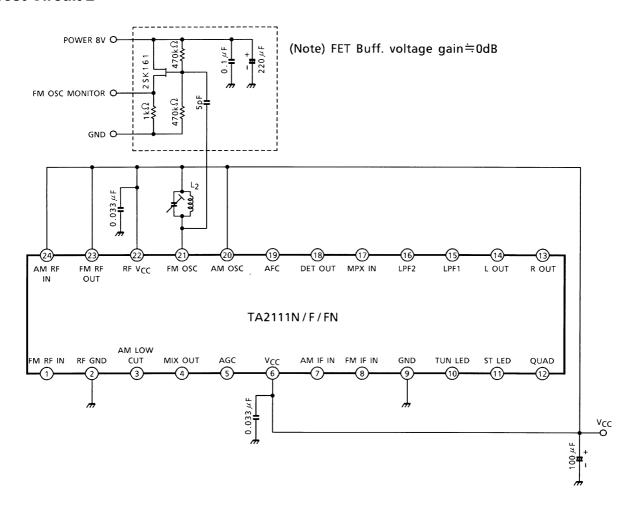
	Characteristics Symbol Test Circuit Test Condition						Min	Тур.	Max	Unit		
Supply current			I _{CC} (FM)	1	Vin = 0, FM mode		1	9	12.5	mA		
Oupply	y Guil e iit		I _{CC (AM)}	1	Vin = 0, AM mode		-	5	7.5			
F/E	Input limiting voltag	Vin (lim)	1	-3dB limiting	_	7	_	dBµV EMF				
	Local OSC voltage		Vosc	2	f _{OSC} = 108.7 MHz		1	105	_	mVrms		
	Input limiting voltag	je	Vin (lim) IF	1	-3dB limiting		35	40	45	dBµV EMF		
	Recovered output v	voltage	V _{OD}	1	Vin = 80dBµV EMF		60	75	90	mVrms		
	Signal to noise ration	0	S/N	1	Vin = 80dBµV EMF		-	65	_	dB		
FM IF	Total harmonic dist	ortion	THD	1	Vin = 80dBµV EMF	,	-	0.2	_	%		
	AM rejection ration		AMR	1	Vin = 80dBµV EMF	,	-	45	_	dB		
	LED on sensitivity		VL	1	I _L = 1 mA		40	45	50	dBµV EMF		
	Soft mute attenuati	on	MUTE	1	Vin = 0		_	20	_	dB		
	Gain		G _V	1	Vin = 25dBµV EMF		18	35	70	mVrms		
	Recovered output voltage		V _{OD}	1	Vin = 60dBµV EMF		50	70	90	mVrms		
AM	Signal to noise ration)	S/N	1	Vin = 60dBµV EMF		_	41	_	dB		
	Total harmonic distortion		THD	1	Vin = 60dBµV EMF		_	0.7	_	%		
	LED on sensitivity		VL	1	I _L = 1 mA	23	28	33	dBµV EMF			
Din 10	Pin 18 output resistance		8 output resistance		В		FM mode	-	0.75	_		
FIII 10			R ₁₈	_	AM mode	_	15.5	_	kΩ			
	Input resistance		R _{IN}		_			55	_	kΩ		
	Output resistance	output resistance			_			5	_	kΩ		
	Max composite signal input voltage		Vin MAX (STEREO)	1	L + R = 90%, P = 10%, f _m = 1 kHz, THD = 3%		_	700	_	mVrms		
					180 mVrms,	f _m = 100 Hz	_	45	_			
	Separation		Sep	1		f _m = 1 kHz	45 — — 45 —		_	dB		
					P = 20 mVrms	f _m = 10 kHz			_	1		
	Total harmonic	Monaural	THD (MONAURAL)	1	Vin = 200 mVrms		_ 0.3 _		_	- %		
MPX	distortion	Stereo	THD (STEREO)	1	L + R = 180 mVrms, P = 20 mVrms		_	0.3	_	70		
	Voltage gain		G _V	1	Vin = 200 mVrms		-2.5	-1	0.5	dB		
	Channel balance		C.B.	1	Vin = 200 mVrms		-1.5	0	1.5	dB		
	Stereo LED ON		V _{L (ON)}	1	Pilot input		_	8	12	mVrms		
	sensitivity OFF		V _{L (OFF)}	1			3	6	_	IIIVIIIIS		
	Stereo LED hysteresis		V _H	1	To LED turn off from LED turn on				_	2	_	mVrms
	Capture range	C.R.	1	P = 20 mVrms	_	±8	_	%				
	Signal to noise ration))	S/N	1	_	_	80	_	dB			

Test Circuit 1



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Test Circuit 2



Coil Data

Coil No.	Toot From L	L	L	Co	0			Turns			Wire	Reference
COII NO.	Test Freq.	(µH)	(pF)	Qo	1-2	2-3	1-3	1-4	4-6	(mmφ)	Reference	
L ₁ FM RF	100 MHz	_	ı	79	_	ı	ı	$2\frac{1}{2}$	ı	0.16UEW	TOKO Co., Ltd. 666SNF-305NK	
L ₂ FM OSC	100 MHz	_	-	76	_	_	_	2		0.16UEW	TOKO Co., Ltd. 666SNF-306NK	
T ₁ AM OSC	796 kHz	268	-	65	19	95	_	_		0.05UEW	TOKO Co., Ltd. 5PNR-5146Y	
T ₂ AM IFT	455 kHz	_	470	60	_		109	_	7	0.05UEW	TOKO Co., Ltd. 5PLG-5147X	

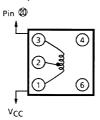




L2: FM OSC



 $\mathsf{T}_1:\mathsf{AM}\ \mathsf{OSC}$



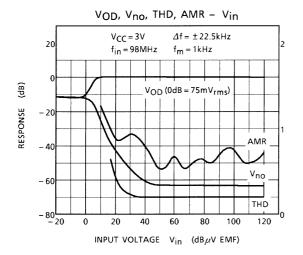
 $T_2: AM\ IFT$ FM C.F. AM C.F. Pin ④ v_{CC}

(BOTTOM VIEW)

(%)

(mA)

FM (F/E+IF)



FM (IF)

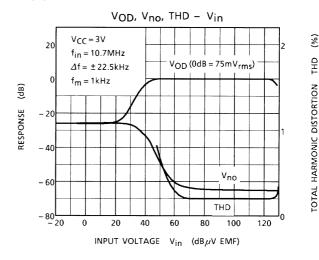
%

THD

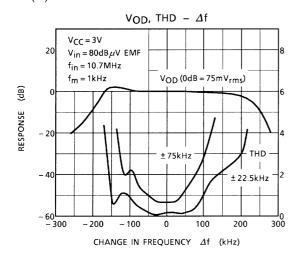
TOTAL HARMONIC DISTORTION

%

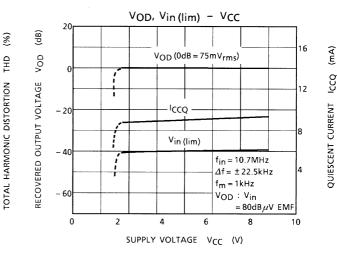
TOTAL HARMONIC DISTORTION



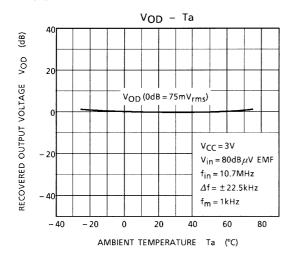
FM (IF)



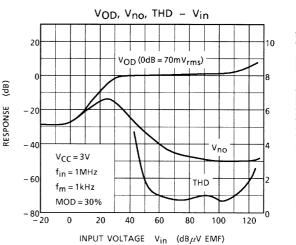
FM (IF)



FM (IF)



 AM

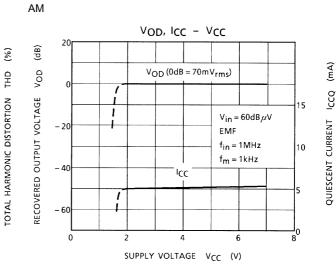


%

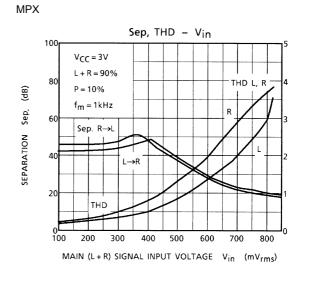
TOTAL HARMONIC DISTORTION THD

AM VOD, THD - MOD 300 V_CC = 3V $100 {
m dB} \mu {
m V}$ EMF $^{\mathsf{V}}^{\mathsf{OD}}$ $f_{in} = 1MHz$ $f_m = 1kHz$ RECOVERED OUTPUT VOLTAGE (mV_{rms}) 200 60 v_{OD} 100 100 60 100 20 40 80

MODULATION MOD (%)



AM V_{OD} - Ta (dB) RECOVERED OUTPUT VOLTAGE VOD 20 V_{OD} (0dB = 70m V_{rms}) $V_{CC} = 3V$ - 20 $V_{in} = 60 dB \mu V EMF$ f_{in} = 1MHz f_m = 1kHz MOD = 30% 80 - 40 - 20 0 20 40 60 AMBIENT TEMPERATURE Ta (°C)



Sep, THD - fm

OULD Sep. L->R

Sep. L->R

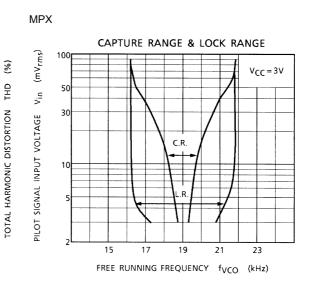
OULD Sep. L->R

OULD Sep. L->R

Sep. L->R

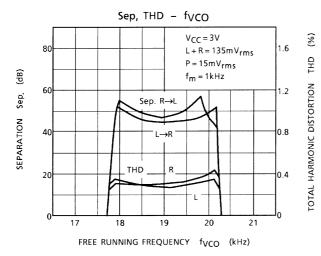
OULD Sep.

MPX

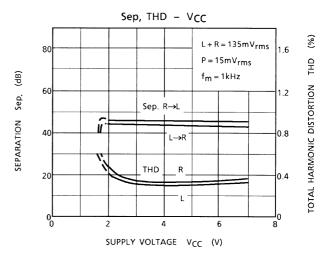


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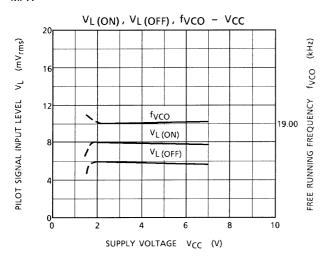
MPX



MPX



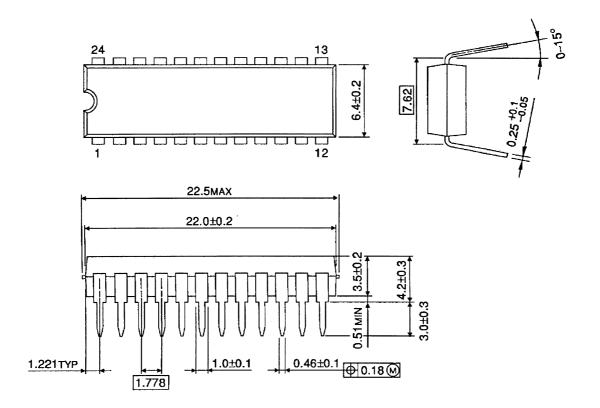
MPX



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Package Dimensions

SDIP24-P-300-1.78 Unit: mm

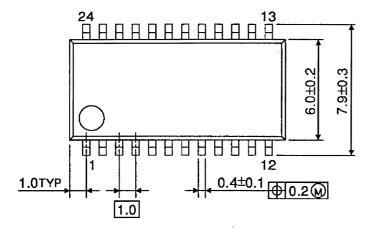


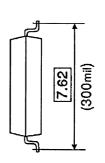
Weight: 1.2 g (typ.)

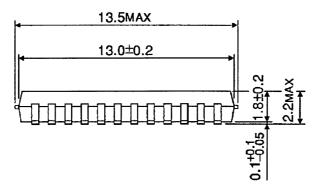
Unit: mm

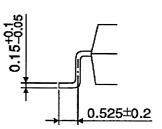
Package Dimensions

SSOP24-P-300-1.00



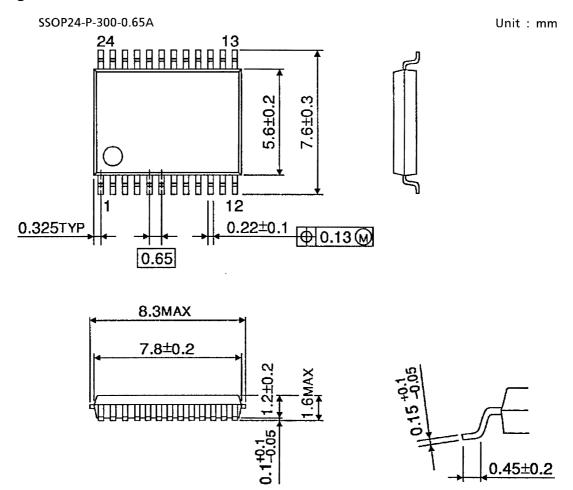






Weight: 0.31 g (typ.)

Package Dimensions



Weight: 0.14 g (typ.)

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000707EBA

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